



Standard Recovery Diodes (Hockey PUK Version), 2100 A



DO-200AB (B-PUK)

FEATURES

- Wide current range
- High voltage ratings up to 1000 V
- High surge current capabilities
- Diffused junction
- Hockey PUK version
- Case style DO-200AB (B-PUK)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

- Converters
- Power supplies
- High power drives
- Auxiliary system supplies for traction applications

PRODUCT SUMMARY	
$I_{F(AV)}$	2100 A
Package	DO-200AB (B-PUK)
Circuit configuration	Single Diode

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		2100	A
	T_{hs}	55	°C
$I_{F(RMS)}$		3900	A
	T_{hs}	25	°C
I_{FSM}	50 Hz	23 900	A
	60 Hz	25 000	
I^2t	50 Hz	2857	kA ² s
	60 Hz	2608	
V_{RRM}	Range	400 to 1000	V
T_J		-40 to 180	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = 180$ °C mA
VS-SD2000C..L	04	400	500	60
	08	800	900	
	10	1000	1100	



FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at heatsink temperature	$I_{F(AV)}$	180° conduction, half sine wave Double side (single side) cooled		2100 (1040)	A
				55 (85)	°C
Maximum RMS forward current	$I_{F(RMS)}$	25 °C heatsink temperature double side cooled		3900	A
Maximum peak, one-cycle forward, non-repetitive surge current	I_{FSM}	t = 10 ms	No voltage reapplied	23 900	
		t = 8.3 ms	No voltage reapplied	25 000	
		t = 10 ms	100 % V_{RRM} reapplied	20 100	
		t = 8.3 ms	100 % V_{RRM} reapplied	21 000	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reapplied	2857	kA ² s
		t = 8.3 ms	No voltage reapplied	2608	
		t = 10 ms	100 % V_{RRM} reapplied	2020	
		t = 8.3 ms	100 % V_{RRM} reapplied	1844	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reapplied		28 570	kA ² √s
Low level value of threshold voltage	$V_{F(TO)1}$	(16.7 % $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J$ maximum		0.74	V
High level value of threshold voltage	$V_{F(TO)2}$	(I > $\pi \times I_{F(AV)}$), $T_J = T_J$ maximum		0.86	
Low level value of forward slope resistance	r_{f1}	(16.7 % $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J$ maximum		0.13	mW
High level value of forward slope resistance	r_{f2}	(I > $\pi \times I_{F(AV)}$), $T_J = T_J$ maximum		0.12	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 6000$ A, $T_J = T_J$ maximum, $t_p = 10$ ms sinusoidal wave		1.55	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction operating temperature range	T_J			-40 to 180	°C
Maximum storage temperature range	T_{Stg}			-55 to 200	
Maximum thermal resistance, junction to heatsink	R_{thJ-hs}	DC operation single side cooled		0.073	K/W
		DC operation double side cooled		0.031	
Mounting force, ± 10 %				14 700 (1500)	N (kg)
Approximate weight				255	g
Case style		See dimensions - link at the end of datasheet		DO-200AB (B-PUK)	

ΔR_{thJ-hs} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.009	0.009	0.006	0.006	$T_J = T_J$ maximum	K/W
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.020	0.021	0.021		
30°	0.036	0.036	0.036	0.036		

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

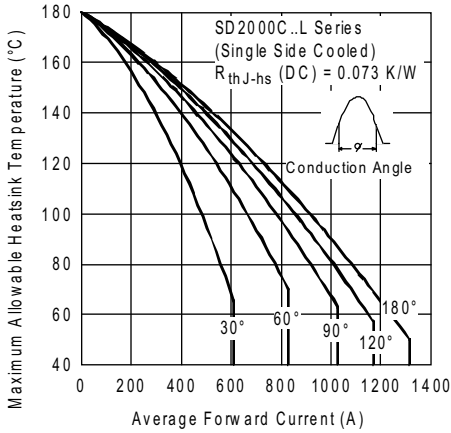


Fig. 1 - Current Ratings Characteristics

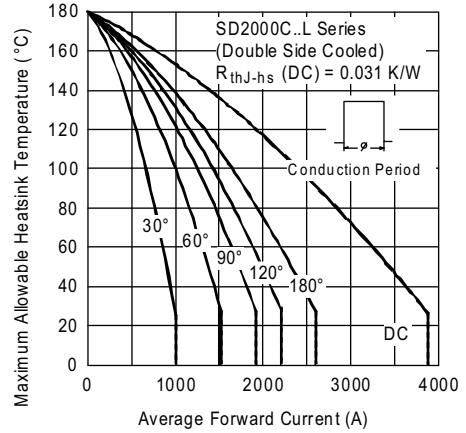


Fig. 4 - Current Ratings Characteristics

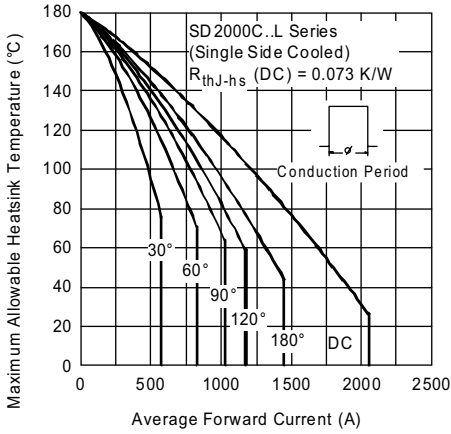


Fig. 2 - Current Ratings Characteristics

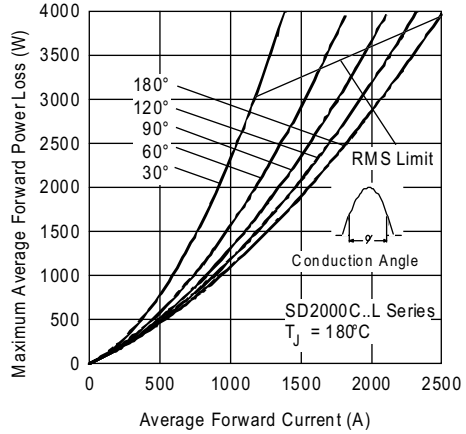


Fig. 5 - Forward Power Loss Characteristics

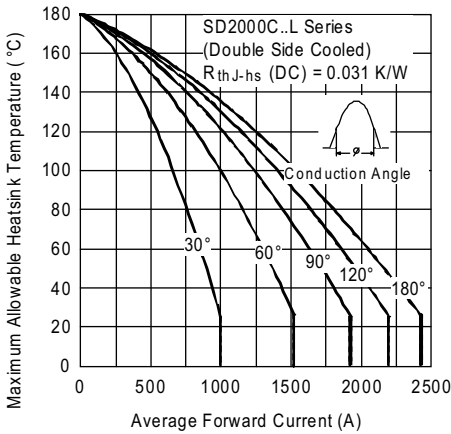


Fig. 3 - Current Ratings Characteristics

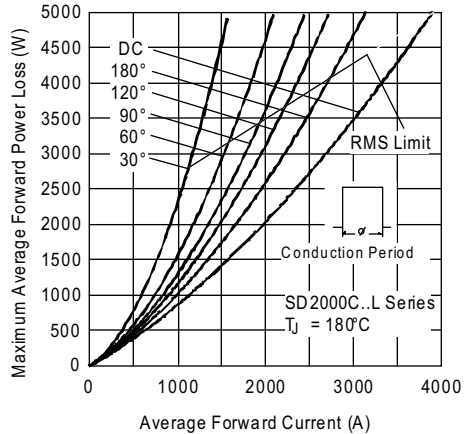


Fig. 6 - Forward Power Loss Characteristics

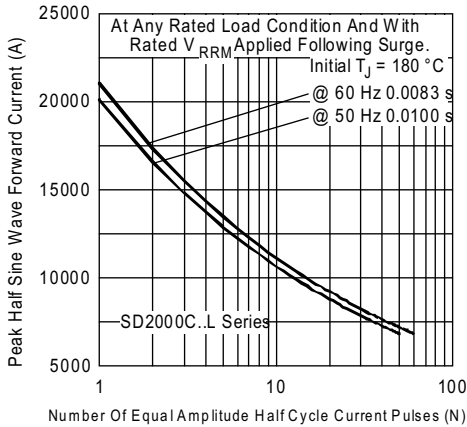


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

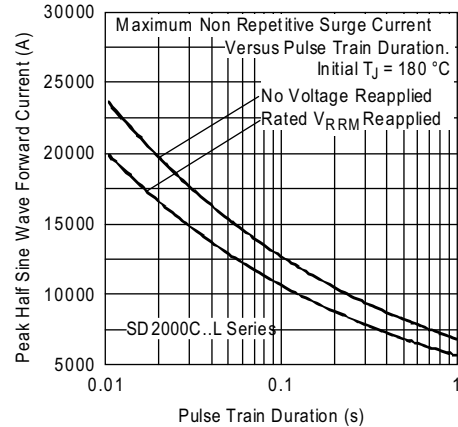


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

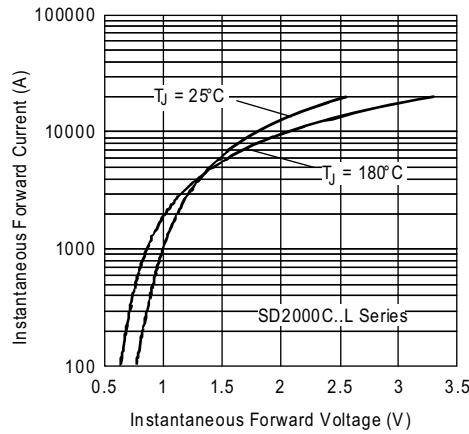


Fig. 9 - Forward Voltage Drop Characteristics

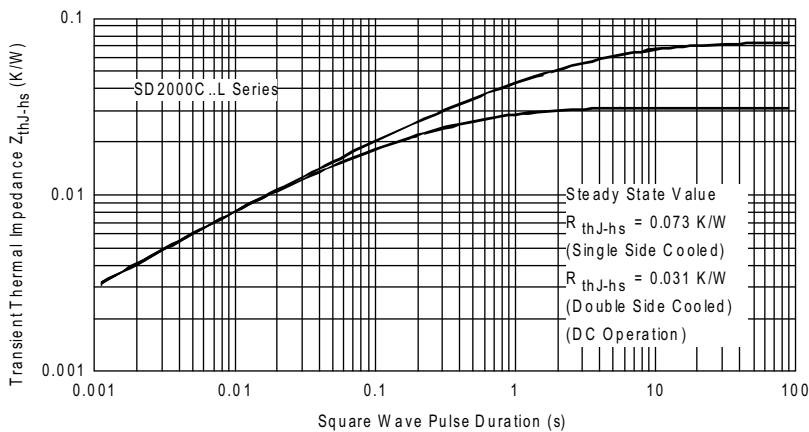
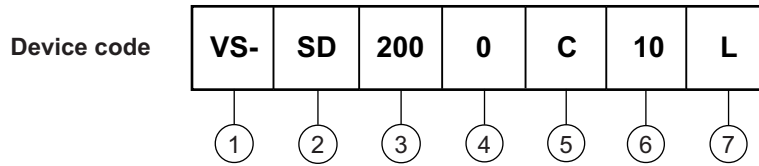


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics



ORDERING INFORMATION TABLE

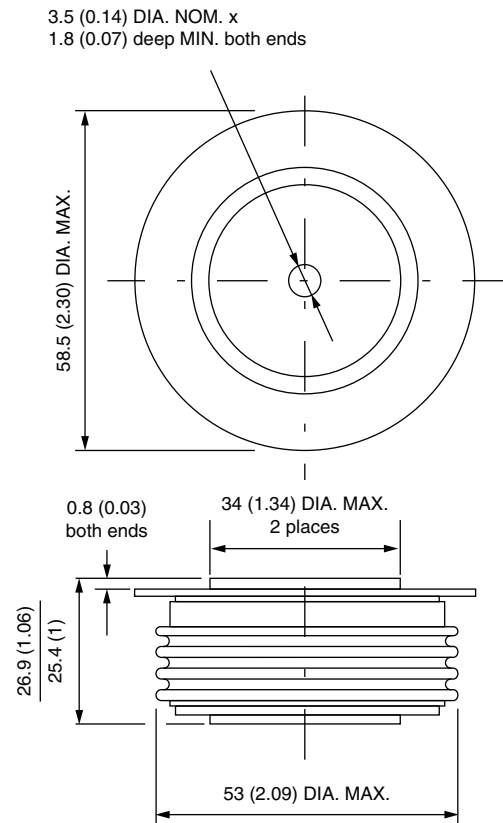


- 1** - Vishay Semiconductors product
- 2** - Diode
- 3** - Essential part number
- 4** - 0 = Standard recovery
- 5** - C = Ceramic PUK
- 6** - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7** - L = PUK case DO-200AB (B-PUK)

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95246

DO-200AB (B-PUK)

DIMENSIONS in millimeters (inches)



Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)



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